

isc Silicon NPN Power Transistor

BUR52

DESCRIPTION

- Collector-Emitter Sustaining Voltage-
: $V_{CEO(SUS)} = 250V(\text{Min})$
- High Current Capability
- Low Saturation Voltage
: $V_{CE(sat)} = 1.0V(\text{Max}) @ I_C = 25A$

APPLICATIONS

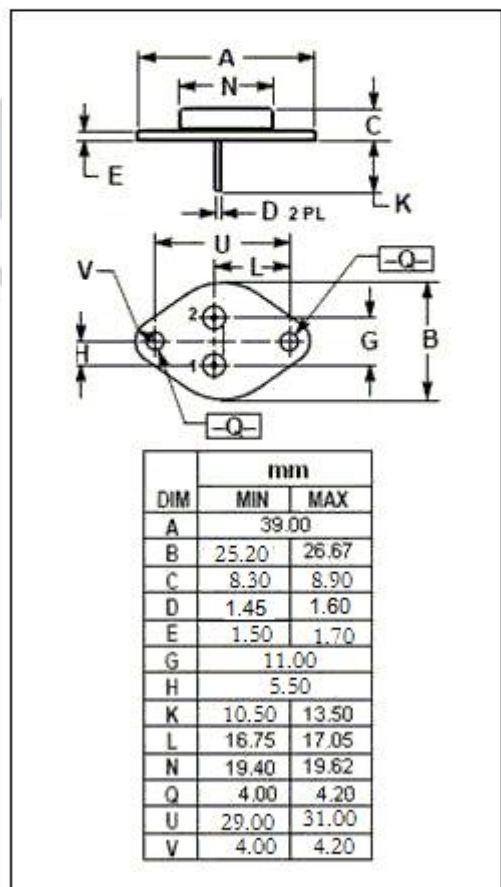
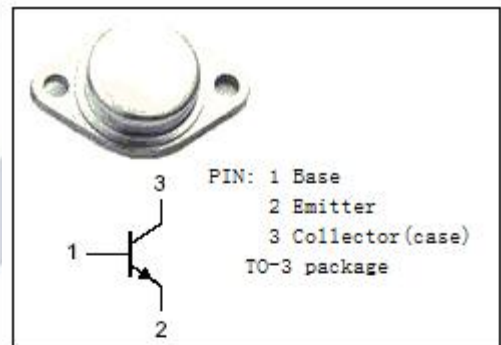
- Designed for switching and linear applications in military and industrial equipment.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	350	V
$V_{CEO(SUS)}$	Collector-Emitter Voltage	250	V
V_{EBO}	Emitter-Base Voltage	10	V
I_C	Collector Current-Continuous	60	A
I_{CM}	Collector Current-Peak	80	A
I_B	Base Current-Continuous	16	A
P_C	Collector Power Dissipation @ $T_C=100^\circ\text{C}$	350	W
T_J	Junction Temperature	200	$^\circ\text{C}$
T_{stg}	Storage Temperature	-65~200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.5	$^\circ\text{C/W}$



isc Silicon NPN Power Transistor**BUR52****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CE0(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=50\text{mA}; I_B=0$	250			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=25\text{A}; I_B=2\text{A}$			1.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=40\text{A}; I_B=4\text{A}$			1.5	V
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C=25\text{A}; I_B=2\text{A}$			1.8	V
$V_{BE(sat)-2}$	Base-Emitter Saturation Voltage	$I_C=40\text{A}; I_B=4\text{A}$			2.0	V
I_{CEO}	Collector Cutoff Current	$V_{CE}=250\text{V}; I_B=0$			1.0	mA
I_{CBO}	Collector Cutoff Current	$V_{CB}=350\text{V}; I_E=0$ $V_{CB}=350\text{V}; I_E=0; T_C=125^\circ\text{C}$			0.2 2	mA
I_{EBO}	Emitter Cutoff Current	$V_{EB}=7\text{V}; I_C=0$			0.2	uA
h_{FE-1}	DC Current Gain	$I_C=5\text{A}; V_{CE}=4\text{V}$	20		100	
h_{FE-2}	DC Current Gain	$I_C=40\text{A}; V_{CE}=4\text{V}$	15			
f_T	Current-Gain—Bandwidth Product	$I_C=1\text{A}; V_{CE}=5\text{V}; f_{test}=10\text{MHz}$		10		MHz